

KSE13008/13009

High Voltage Switch Mode Application

- High Speed Switching
- Suitable for Switching Regulator and Motor Control



1.Base 2.Collector 3.Emitter

NPN Silicon Transisor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CBO}	Collector-Base Voltage			
	: KSE13008	600	V	
	: KSE13009	700	V	
V _{CEO}	Collector-Emitter Voltage			
	: KSE13008	300	V	
	: KSE13009	400	V	
V _{EBO}	Emitter-Base Voltage	9	V	
I _C	Collector Current (DC)	12	А	
I _{CP}	Collector Current (Pulse)	24	А	
I _B	Base Current	6	А	
P _C	Collector Dissipation (T _C =25°C)	100	W	
TJ	Junction Temperature	150	°C	
T _{STG}	Storage Temperature	- 65 ~ 150	°C	

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V _{CEO} (sus)	Collector-Emitter Sustaining Voltage : KSE13008 : KSE13009	I _C = 10mA, I _B = 0	300 400			V V
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 9V, I_{C} = 0$			1	mA
h _{FE}	* DC Current Gain	$V_{CE} = 5V, I_{C} = 5A$ $V_{CE} = 5V, I_{C} = 8A$	8 6		40 30	
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	$I_C = 5A, I_B = 1A$ $I_C = 8A, I_B = 1.6A$ $I_C = 12A, I_B = 3A$			1 1.5 3	V V V
V _{BE} (sat)	* Base-Emitter Saturation Voltage	$I_C = 5A, I_B = 1A$ $I_C = 8A, I_B = 1.6A$			1.2 1.6	V V
C _{ob}	Output Capacitance	V _{CB} = 10V, f = 0.1MHz		180		pF
f _T	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.5A$	4			MHz
t _{ON}	Turn On Time	$V_{CC} = 125V, I_{C} = 8A$			1.1	μs
t _{STG}	Storage Time	$I_{B1} = -I_{B2} = 1.6A$			3	μs
t _F	Fall Time	$R_L = 15,6\Omega$			0.7	μs

^{*} Pulse test: PW≤300μs, Duty cycle≤2%

Typical Characteristics

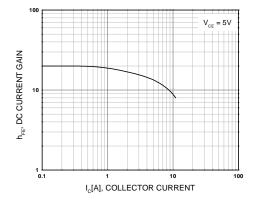


Figure 1. DC current Gain

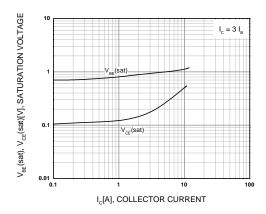


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

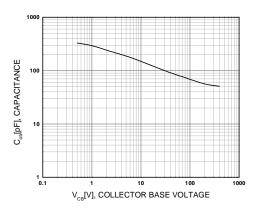


Figure 3. Collector Output Capacitance

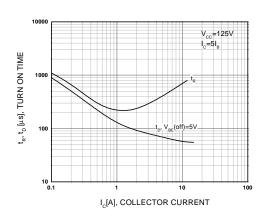


Figure 4. Turn On Time

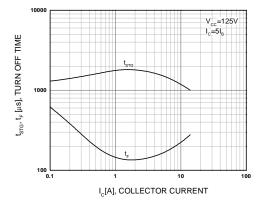


Figure 5. Turn Off Time

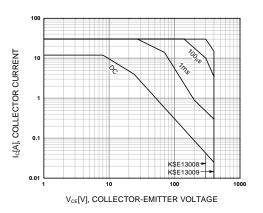


Figure 6. Safe Operating Area

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Typical Characteristics (Continued)

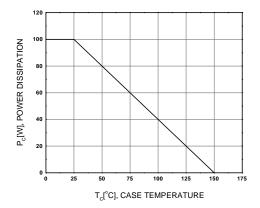
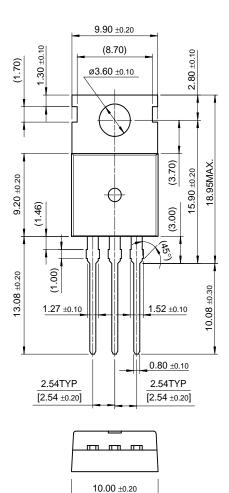
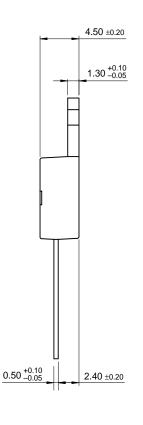


Figure 7. DC current Gain

Package Demensions

TO-220





Dimensions in Millimeters

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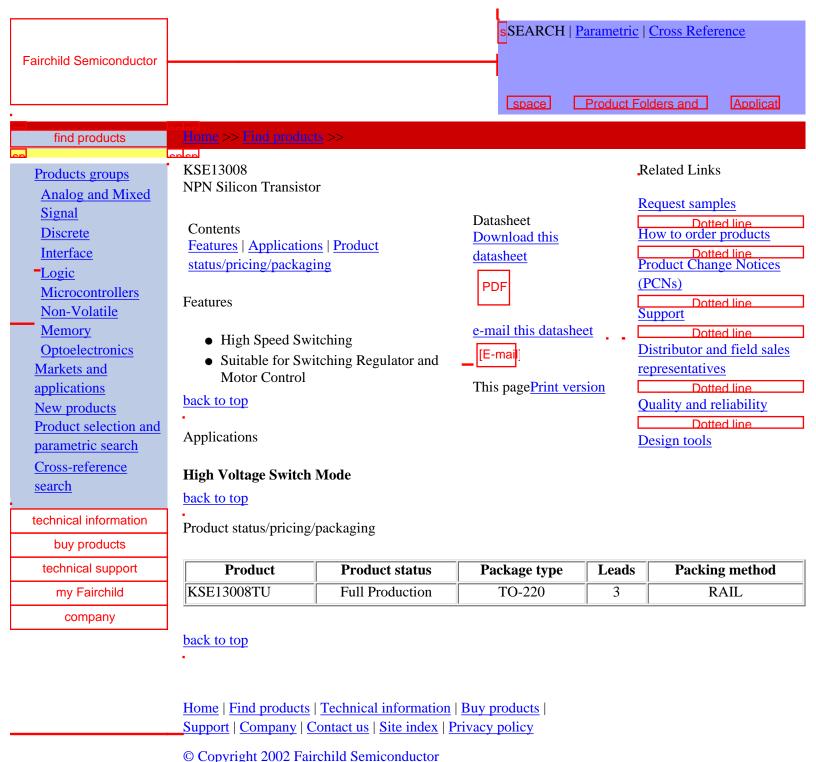
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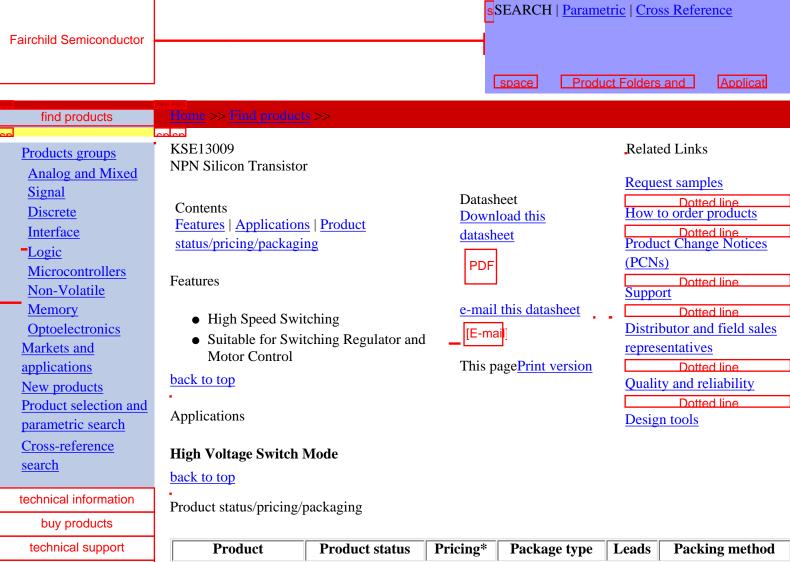
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Product	Product status	Pricing*	Package type	Leads	Packing method
KSE13009H2	Full Production	\$0.81	TO-220	3	BULK
KSE13009H2TU	Full Production	\$0.81	TO-220	3	RAIL
KSE13009	Full Production	\$0.81	TO-220	3	BULK
KSE13009TU	Full Production	\$0.81	TO-220	3	RAIL

^{* 1,000} piece Budgetary Pricing

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